TOSHIBA Photocoupler IRED & Photo-Transistor

TLP570, TLP571

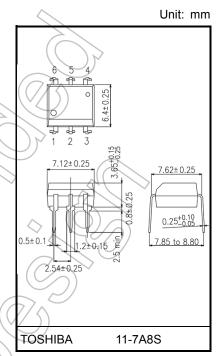
Programmable Controllers AC / DC-Input Module Solid State Relay

The TOSHIBA TLP570 and TLP571 consist of a Darlington connected photo-transistor optically coupled to an infrared emitting diode in a six lead plastic DIP package.

TLP570 has no-base internal connection for high-EMI environments.

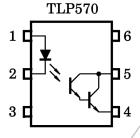
- Collector-emitter voltage: 35 V (min)
- Current transfer ratio: 1000 % (min)
- Isolation voltage: 2500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349



Weight: 0.4 g (typ.)

Pin Configurations (top view)



1: ANODE

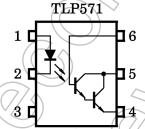
2: CATHODE

3: NC

4 : EMITTER

5 : COLLECTOR

6: NC



1: ANODE

2: CATHODE

3: NC

4 : EMITTER

5 : COLLECTOR

6: BASE



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	70	mA
	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	IFP	1	A
LED	Reverse voltage	VR	5	V
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta >25°C)	ΔP _D /°C	-1.0	mW/°C
	Junction temperature	Tj	125	(°C)
	Collector-emitter voltage	V _{CEO}	35	V
	Collector-base voltage (TLP571)	V _{CBO}	80))v
	Emitter-collector voltage	V _{ECO}	7	٧
Detector	Emitter-base voltage (TLP571)	V _{EBO}	7	V
Dete	Collector current	Ic	150	mA
	Power dissipation	Pc	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C / °C	-1.5	mW / °C
	Junction temperature	Ji)	125	(%
Storage temperature range		T _{stg}	-55 to 125	°C
Operating temperature range		Topr	-55 to 100	//
Lead soldering temperature (10 s)		T _{sol}	260	Ĵ.c
Total package power dissipation		PT	250	mW
Tota	ll package power dissipation derating (Ta ≥ 25°C)	ΔP _T / °C	-2.5	mW / °C
Isola	ation voltage (AC, 60 s, R.H.≤ 60 %) (Note 1)	BVS	2500	V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal: Pins1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommends Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply-voltage	Vcc	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	_	50	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz		30	-	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 1 mA	35			V
	Emitter-collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1 mA	Z)'-	_	V
Detector	Collector-base breakdown voltage (TLP571)	V _(BR) CBO	I _C = 0.1 mA	80	_	_	V
	Emitter-base breakdown voltage (TLP571)	V(BR)EBO	IE = 0.1 mA	7	-		٧
	Collector dark current	loco	VCE = 24 V	_	10	200	nA
۵	Collector dark current	ICEO	V _{CE} = 24 V, Ta = 85 °C	_	4	300	μΑ
	Collector dark current (TLP571)	ICER	V _{CE} = 24 V, Ta = 85 °C R _{BE} = 10 MΩ	7	0.5	10	μА
	Collector dark current (TLP571)	Ісво	V _{CB} = 10 V	7	0.01)	_	nA
	DC forward current gain (TLP571)	hFE	V _{CE} = 5 V, I _C = 10 mA	7	50k	_	_
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz		10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	Ic/IF	I _F = 1 mA, V _{CE} = 1 V	1000	2000	_	%
Saturated CTR	IC / IF (sat)	IF = 10 mA, VCE = 1 V	500	_	_	%
Base photo-current (TLP571)	lpв	I _F = 1 mA, V _{CB} = 1 V	-	2	_	μΑ
Collector-emitter saturation voltage	\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	IC = 10 mA, IF = 1 mA	١	_	1.0	V
	VCE (sat)	IC = 100 mA, IF = 10 mA	0.3	_	1.2	V



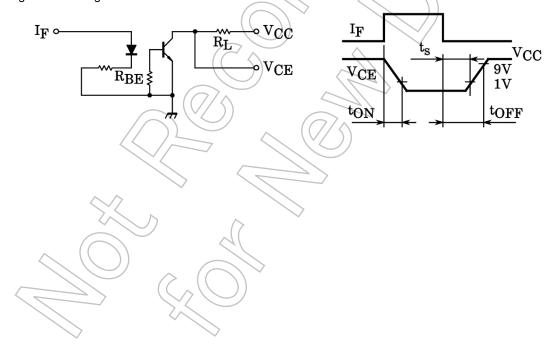
Isolation Characteristics (Ta = 25°C)

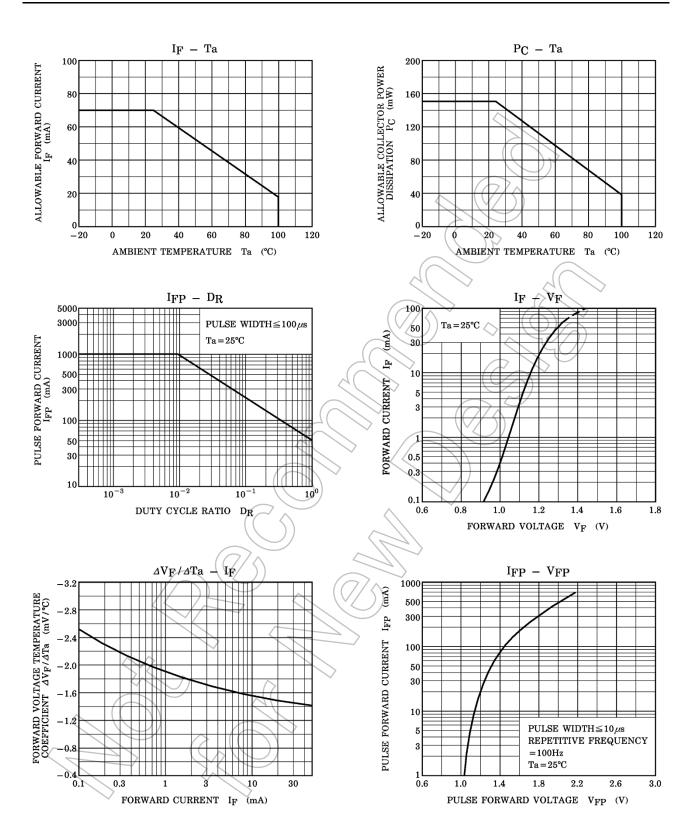
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	_	8.0	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	2500	_	_	V _{rms}

Switching Characteristics (Ta = 25°C)

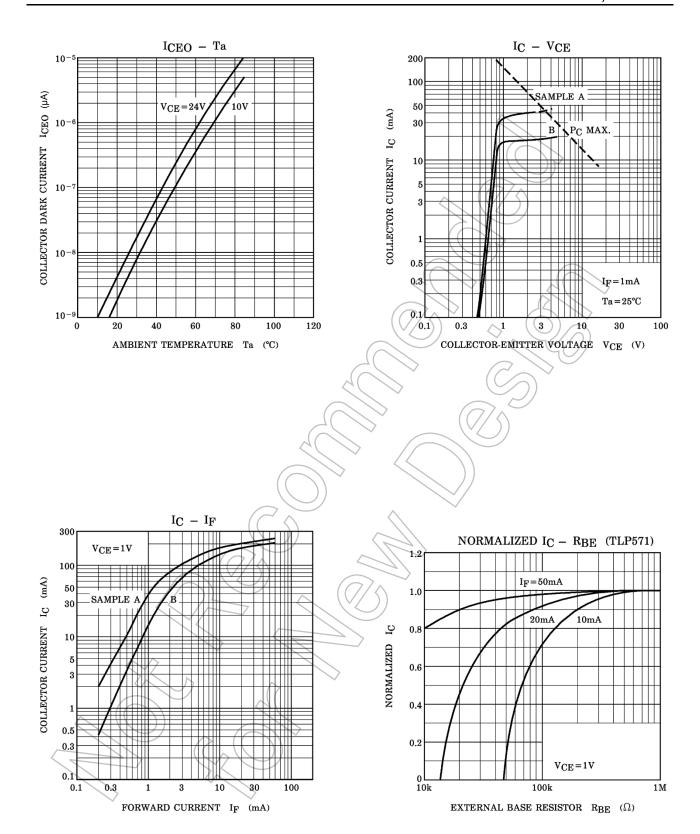
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr		_	40	_	
Fall time	t _f	V _{CC} = 10 V	_	30	_	
Turn-on time	ton	I _C = 10 mA R _L = 100 Ω	_	45	_	μS
Turn-off time	toff		- 0	35		
Turn-on time	ton	$R_L = 180 \Omega$ (Fig.4)	10	5	· –	
Storage time	ts	R _{BE} = open	7	(20)) —	μS
Turn-off time	toff	V _{CC} = 10 V, I _F = 10 mA	7	100	_	
Turn-on time	ton	\(\) \(\)		5	_	
Storage time	ts	$R_L = 180 \Omega$ (Fig.1) $R_{BE} = 10 M\Omega (TLP571)$		15	_	μS
Turn-off time	toff	VCC = 10 V, IF = 10 mA) —	60	_	

Fig. 1 Switching time test circuit

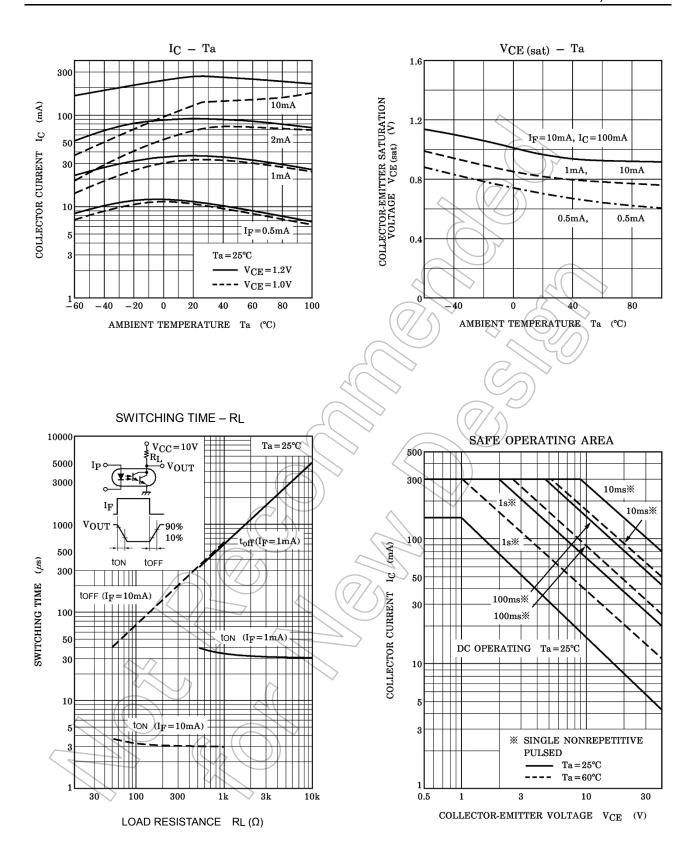




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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